

Lab-based correlative X-ray imaging to study core formation and its impact on lattice uniformity in (Mg,Zr):SrGa₁₂O₁₉ single crystals

C. Richter¹, C. Gugushev¹, M. Brützam¹, K. Dadzis¹, J. Schreuer², C. Hirschle², T.M. Gesing^{3,4}, A. Kwasniewski¹, D. G. Schlom^{5,6,1}

¹Leibniz-Institut für Kristallzüchtung, Max-Born-Str. 2, 12489 Berlin, Germany

²Institut für Geologie, Mineralogie und Geophysik, Ruhr-Universität Bochum, Universitätsstraße 150, 44801 Bochum, Germany

³University of Bremen, Solid State Chemical Crystallography, Institute of Inorganic Chemistry and Crystallography/FB02, Leobener Str. 7, Germany

⁴MAPEX Center for Materials and Processes, Bibliothekstraße 1, D-28359 Bremen, Germany

⁵Department of Materials Science and Engineering, Cornell University, Ithaca, NY 14853-1501, USA

⁶Kavli Institute at Cornell for Nanoscale Science, Ithaca, NY 14853, USA

E-mail: carsten.richter@ikz-berlin.de

We demonstrate the growth of large (Mg,Zr):SrGa₁₂O₁₉ (SGMZ) single crystals and use a combination of X-ray imaging techniques to analyze them structurally and chemically. Single crystal cylinders were obtained by top-seeded solution growth with optimized melt compositions. In the central parts of the grown crystals, we have observed stress-induced birefringence. As a possible explanation, we considered the formation of a small (0001) facet at the central part of the growth interface that should have a detectable impact on both the chemical composition and the crystal lattice. To test this assumption, we developed a quantitative rocking curve imaging technique (Fig. 1) with high sensitivity to study subtle variations of the microstructure.

This method enabled us to observe that the core region exhibits a reduced unit cell volume and is surrounded by a ring with increased lattice tilt and elastic strain. These effects were also analyzed using numerical simulations of the three-dimensional elastic stress and strain fields. Furthermore, variations of the cell volume in the outer parts of the crystal reveal a slight in-plane anisotropy of dopant incorporation following the hexagonal crystallographic symmetry. The relationship between unit cell dimensions and composition was verified by micro X-ray fluorescence mappings.

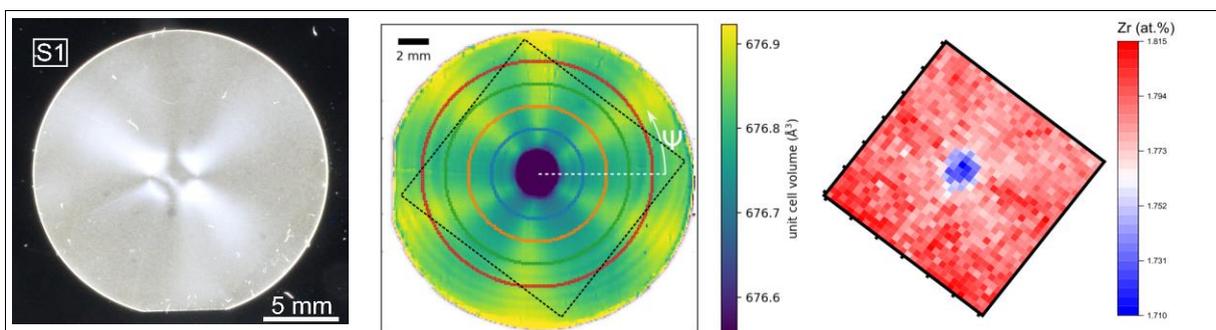


Fig 1: Determined maps of birefringence (left), unit cell volume (center) and Zr-fluorescence (right) of a 0001 cut SGMZ wafer.